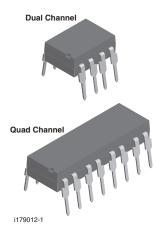
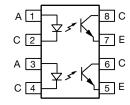
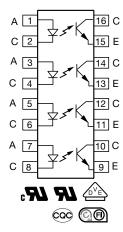


Optocoupler, Phototransistor Output (Dual, Quad Channel)







LINKS TO ADDITIONAL RESOURCES









DESCRIPTION

The ILD615, ILQ615 are multi-channel phototransistor optocouplers that use GaAs IRED emitters and high gain NPN phototransistors. These devices are constructed using over / under leadframe optical coupling and double molded insulation technology resulting a withstand test voltage of $7500 \text{ VAC}_{\text{PEAK}}$ and a working voltage of $1700 \text{ V}_{\text{RMS}}$.

The binned min./max. and linear CTR characteristics make these devices well suited for DC or AC voltage detection. Eliminating the phototransistor base connection provides added electrical noise immunity from the transients found in many industrial control environments.

Because of guaranteed maximum non-saturated and saturated switching characteristics, the ILD615, ILQ615 can be used in medium speed data I/O and control systems. The binned min. / max. CTR specification allow easy worst case interface calculations for both level detection and switching applications. Interfacing with a CMOS logic is enhanced by the guaranteed CTR at $I_{\text{F}} = 1$ mA.

FEATURES

- · Identical channel to channel footprint
- · Dual and quad packages feature:
 - Reduced board space
 - Lower pin and parts count
 - Better channel to channel CTR match
 - Improved common mode rejection
- Isolation rated voltage from double molded package, 4420 V_{RMS}
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

AGENCY APPROVALS

- UL 1577
- cUL
- DIN EN 60747-5-5 (VDE 0884-5), available with option 1
- CQC: GB8898
- FIMKO





RoHS



ORDERING	INFORMATI	ON						
	X 6 PART NUMBER D (Dual) or Q (Qua	1 5 ad)	- # CTR BIN	PACKA	# E	# TAPE AND REEL	7.62 mm Option 7	Option 6 10.16 mm Option 9 > 0.1 mm
AGENCY		DUAL C	HANNEL			QUA	D CHANNEL	
CERTIFIED / PACKAGE	CTR (%)							
				10 n				
UL, CSA	40 to 80	63 to 125	100 to 200	160 to 320	40 to 80	63 to 125	100 to 200	160 to 320
DIP-8	ILD615-1	ILD615-2	ILD615-3	ILD615-4	=	=	=	=
DIP-8, 400 mil, option 6	-	-	-	ILD615-4X006	-	-	-	-
SMD-8, option 7	ILD615-1X007 T ⁽¹⁾	-	-	-	-	-	-	-
SMD-8, option 9	-	ILD615-2X009T	ILD615-3X009T	ILD615-4X009T	-	-	-	-
DIP-16	-	-	-	-	ILQ615-1	ILQ615-2	ILQ615-3	ILQ615-4
SMD-16, option 7	-	-	-	-	-	ILQ615-2X007	ILQ615-3X007T	-
SMD-16, option 9	-	-	-	-	ILQ615-1X009	-	ILQ615-3X009T (1)	ILQ615-4X009T (1)
UL, CSA, VDE	40 to 80	63 to 125	100 to 200	160 to 320	40 to 80	63 to 125	100 to 200	160 to 320
DIP-8	-	ILD615-2X001	-	ILD615-4X001	-	-	-	-
DIP-8, 400 mil, option 6	-	ILD615-2X016	-	ILD615-4X016	ī	-	-	-
SMD-8, option 7	-	-	ILD615-3X017T (1)	-	-	=	-	-
DIP-16	-	-	-	-	-	-	-	ILQ615-4X001
DIP-16, 400 mil, option 6	-	-	-	-	-	-	ILQ615-3X016	-

Notes

- · Additional options may be possible, please contact sales office
- (1) Also available in tubes; do not add T to end

ABSOLUTE MAXIMUM RATINGS	(T _{amb} = 25 °C, unless otherw	vise specified)		
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT				
Reverse voltage		V _R	6	V
Forward current		I _F	60	mA
Surge current		I _{FSM}	1.5	Α
Power dissipation		P _{diss}	100	mW
Derate linearly from 25 °C			1.33	mW/°C
OUTPUT				
Collector emitter breakdown voltage		BV _{CEO}	70	V
Emitter collector breakdown voltage		BV _{ECO}	7	V
Collector current		I _C	50	mA
Collector current	t < 1 ms	I _C	100	mA
Power dissipation		P _{diss}	150	mW
Derate linearly from 25 °C			2	mW/°C



ABSOLUTE MAXIMUM RATINGS	(T _{amb} = 25 °C, unless otherw	ise specified)		
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
COUPLER				
Storage temperature		T _{stg}	-55 to +150	°C
Operating temperature		T_{amb}	-55 to +100	°C
Junction temperature		Tj	100	°C
Soldering temperature (1)	2 mm distance from case bottom	T _{sld}	260	°C
Package power dissipation ILD615			400	mW
Derate linearly from 25 °C			5.33	mW/°C
Package power dissipation ILQ615			500	mW
Derate linearly from 25 °C			6.67	mW/°C
Total power dissipation		P _{tot}	250	mW

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
 implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
 maximum ratings for extended periods of the time can adversely affect reliability.
- (2) Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT						L
Forward voltage	I _F = 10 mA	V _F	1	1.15	1.3	V
Breakdown voltage	I _R = 10 μA	V_{BR}	6	30	=	V
Reverse current	V _R = 6 V	I _R	=	0.01	10	μΑ
Capacitance	$V_R = 0 V, f = 1 MHz$	Co	=	25	-	рF
Thermal resistance, junction to lead		R _{THJL}	-	750	-	K/W
OUTPUT						
Collector emitter capacitance	V _{CE} = 5 V, f = 1 MHz	C _{CE}	-	6.8	-	pF
Collector emitter leakage current, -1, -2	V _{CE} = 10 V	I _{CEO}	-	2	50	nA
Collector emitter leakage current, -3, -4	V _{CE} = 10 V	I _{CEO}	-	5	100	nA
Collector emitter breakdown voltage	I _{CE} = 0.5 mA	BV _{CEO}	70	-	-	V
Emitter collector breakdown voltage	I _E = 0.1 mA	BV _{ECO}	7	-	-	V
Thermal resistance, junction to lead		R _{THJL}	-	500	-	K/W
PACKAGE TRANSFER CHARACTERISTICS						
Channel/channel CTR match	$I_F = 10 \text{ mA}, V_{CE} = 5 \text{ V}$	CTRX/CTRY	1 to 1	-	2 to 1	
COUPLER						
Capacitance (input to output)	V _{IO} = 0 V, f = 1 MHz	C _{IO}	-	0.8	-	pF
Channel to channel isolation			500	-	-	VAC

Note

Minimum and maximum values are tested requirements. Typical values are characteristics of the device and are the result of engineering
evaluations. Typical values are for information only and are not part of the testing requirements.

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
		ILD615-1	CTD		05		%
		ILQ615-1	CTR _{CEsat}	-	MIN. TYP. MAX. - 25 - - 40 - - 60 - - 100 - 13 30 - 22 45 - 34 70 - 56 90 - 40 60 80 63 80 125 100 150 200 160 200 320	%0	
		ILD615-2	CTR _{CEsat}		40	80 125 200	%
Current transfer ratio	$I_F = 10 \text{ mA}, V_{CE} = 0.4 \text{ V}$	ILQ615-2	OTHCEsat		40		70
(collector emitter saturated)	IF = 10 III/A, VCE = 0.4 V	ILD615-3	- CTR _{CEsat}	_	60		%
		ILQ615-3	OTTICESat		00		70
		ILD615-4	- CTR _{CEsat}	_	100	_	%
		ILQ615-4	OTTICESAT		100	- - - - - - 80 125 200	70
		ILD615-1	CTR _{CF}	13	30	- - - - - - 80	%
	I _F = 1 mA, V _{CE} = 5 V	ILQ615-1	OTTICE	10			,,,
		ILD615-2	- CTR _{CE}	22	45	80 125 200	%
		ILQ615-2			10		,,,
	1F - 1 111/1, VGE - 0 V	ILD615-3	CTR _{CE}	34	70		%
		ILQ615-3	OTTICE	0-1	70		70
		ILD615-4	CTR _{CE}	56	90	_	%
Current transfer ratio		ILQ615-4	OTTICE		00		70
(collector emitter)		ILD615-1	CTR _{CE}	40	60	80	%
		ILQ615-1	OTTICE	40	00	- - - - - - 80 125 200	70
		ILD615-2	CTR _{CE}	63	80	125	%
	$I_{\rm F} = 10 \text{mA}, V_{\rm CF} = 5 \text{V}$	ILQ615-2	OTTICE		00	120	70
	1F = 10 11177, VOE = 3 V	ILD615-3	CTR _{CF}	100	150	40 - 60 - 10	%
		ILQ615-3	OTTICE	100	100		/0
		ILD615-4	CTR _{CE}	160	200		%
		ILQ615-4	OTTICE	100	200	020	/0

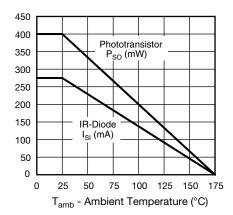


Fig. 1 - Derating Diagram

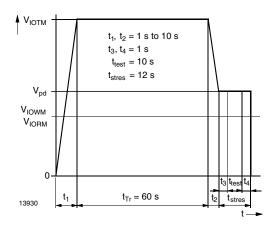


Fig. 2 - Test Pulse Diagram for Sample Test According to DIN EN 60747-5-2 (VDE0884); IEC60747-5-5



PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
NON-SATURATED							
Current	$V_{CC} = 5 \text{ V}, R_L = 75 \Omega, 50 \% \text{ of } V_{PP}$		I _F	-	10	_	mA
Turn-on time	$V_{CC} = 5 \text{ V}, R_L = 75 \Omega, 50 \% \text{ of } V_{PP}$		t _{on}	-	3	-	μs
Rise time	$V_{CC} = 5 \text{ V}, R_L = 75 \Omega, 50 \% \text{ of } V_{PP}$		t _r	-	2	-	μs
Turn-off time	$V_{CC} = 5 \text{ V}, R_L = 75 \Omega, 50 \% \text{ of } V_{PP}$		t _{off}	-	2.3	-	μs
Fall time	$V_{CC} = 5 \text{ V}, R_L = 75 \Omega, 50 \% \text{ of } V_{PP}$		t _f	-	2	-	μs
Propagation H to L	$V_{CC} = 5 \text{ V}, R_L = 75 \Omega, 50 \% \text{ of } V_{PP}$		t _{PHL}	-	1.1	_	μs
Propagation L to H	$V_{CC} = 5 \text{ V}, R_L = 75 \Omega, 50 \% \text{ of } V_{PP}$		t _{PLH}	-	2.5	-	μs
SATURATED	100 11,12 111,111		7-01		1		_ F
		ILD615-1					
		ILQ615-1	- I _F	-	20	-	mA
		ILD615-2					
	$V_{CC} = 5 \text{ V}, R_L = 1 \text{ k}\Omega,$	ILQ615-2	I _F	-	10	-	mA
Current	$V_{\text{CC}} = 3 \text{ V}, \text{ H}_{\text{L}} = 1.5 \text{ V}$	ILD615-3					
		ILQ615-3	I _F	-	10	-	mA
		ILD615-4					
		ILQ615-4	I _F	-	5	-	mA
		ILD615-1					
		ILQ615-1	t _{on}	-	3	-	μs
		ILD615-2					
	V 5V D 110	ILQ615-2	t _{on}	-	4.3	-	μs
Turn-on time	V_{CC} = 5 V, R_L = 1 k Ω , V_{TH} = 1.5 V	ILD615-3					
	118	ILQ615-3	t _{on}	-	4.3	-	μs
		ILQ015-3					
		ILQ615-4	t _{on}	-	6	-	μs
		ILQ015-4					
		ILQ1615-1	t _r	-	2	-	μs
		ILD615-2					
	V 5VD 110	ILQ615-2	t _r	-	2.8	-	μs
Rise time	V_{CC} = 5 V, R_L = 1 k Ω , V_{TH} = 1.5 V	ILQ015-2					
	VIH = 1.5 V	ILQ615-3	t _r	-	2.8	-	μs
		ILQ015-3					
		ILQ615-4	t _r	-	4.6	-	μs
		ILQ015-4					
		ILQ615-1	t _{off}	-	18	-	μs
		ILD615-2					
	V 5VD 110	ILQ615-2	t _{off}	-	25	-	μs
Turn-off time	V_{CC} = 5 V, R_L = 1 k Ω , V_{TH} = 1.5 V	ILQ015-2					
	VIII = 1.5 V	ILQ615-3	t _{off}	-	25	-	μs
		ILQ015-3					
		ILQ615-4	t _{off}	-	25	-	μs
		ILQ615-4	-				
		ILQ615-1	t _f	-	11	-	μs
			1				
	V 5V 5	ILD615-2 ILQ615-2	t _f	-	14	-	μs
Fall time	$V_{CC} = 5 \text{ V}, R_L = 1 \text{ k}\Omega, \ V_{TH} = 1.5 \text{ V}$						
	VIH - 1.5 V	ILD615-3	t _f	-	14	-	μs
		ILQ615-3					
		ILD615-4 ILQ615-4	t _f	-	15	-	μs



SWITCHING CHARACTE	ERISTICS (T _{amb} = 25 °C, unless	otherwise s	pecified)				
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
SATURATED							
		ILD615-1	+		1.6		110
		ILQ615-1	t _{PHL}	- 1.6 - 2.6	_	μs	
		ILD615-2	+		1.6 - 2.6 - 2.6 - 5.4 - 8.6 - 7.2 - 7.2 -		110
Propagation H to L	$V_{CC} = 5 \text{ V}, R_L = 1 \text{ k}\Omega,$	ILQ615-2	t _{PHL}	_	2.0	6 - 6 - 6 - 6 - 6 - 6 - 6 - 6 - 6 - 6 -	μs
Propagation in to L	V _{TH} = 1.5 V	ILD615-3	+		2.6		110
		ILQ615-3	t _{PHL}	_	2.0	1.6 - 2.6 - 2.6 - 5.4 - 8.6 - 7.2 - 7.2 -	μs
		ILD615-4	+		5.4		110
		ILQ615-4	t _{PHL}	_	3.4		μs
		ILD615-1	+		9.6		110
		ILQ615-1	t _{PLH}	_	0.0	-	μs
		ILD615-2	t	_	7.2	_	116
Propagation L to H	$V_{CC} = 5 \text{ V}, R_L = 1 \text{ k}\Omega,$	ILQ615-2	t _{PLH}	_	1.2		μs
1 Topagation L to 11	V _{TH} = 1.5 V	ILD615-3	t		7.2		He
		ILQ615-3	t _{PLH}	_	1.2		μs
		ILD615-4	+		7.1		110
		ILQ615-4	t _{PLH}	_	7.4	_	μs

COMMON MODE TRANSIENT IMMUNITY (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Common mode rejection output high	$V_{CM} = 50 V_{P-P}, R_L = 1 k\Omega, I_F = 0 mA$	CM _H	-	5000	-	V/µs		
Common mode rejection output low	$V_{CM} = 50 V_{P-P}, R_L = 1 k\Omega, I_F = 0 mA$	CML	-	5000	-	V/µs		
Common mode coupling capacitance		C _{CM}	=	0.01	-	pF		

SAFETY AND INSULATION RATINGS				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Climatic classification	According to IEC 68 part 1		55 / 100 / 21	
Comparative tracking index		CTI	175	
Maximum rated withstanding isolation voltage	t = 1 min	V _{ISO}	4420	V _{RMS}
Maximum transient isolation voltage		V _{IOTM}	10 000	V _{peak}
Maximum repetitive peak isolation voltage		V _{IORM}	890	V _{peak}
	V _{IO} = 500 V, T _{amb} = 25 °C	R _{IO}	≥ 10 ¹²	Ω
Isolation resistance	V _{IO} = 500 V, T _{amb} = 100 °C	R _{IO}	$55 / 100 / 21$ 175 4420 $10 000$ 890 $\geq 10^{12}$ $\geq 10^{11}$ $\geq 10^{9}$ 400 275 175 ≥ 7 ≥ 7 ≥ 0.4 1.669	Ω
isolation registarios	V _{IO} = 500 V, T _{amb} = 175 °C (construction test only)	R _{IO}	≥ 10 ⁹	Ω
Output safety power		P _{SO}	400	mW
Input safety current		I _{SI}	275	mA
Safety temperature		T _S	175	°C
Creepage distance			≥ 7	mm
Clearance distance			≥ 7	mm
Insulation thickness		DTI	≥ 0.4	mm
Partial discharge test voltage - routine test	100 %, t _{test} = 1 s	V_{pd}	1.669	kV _{peak}
Partial discharge test voltage - lot test (sample test	$t_{Tr} = 60 \text{ s}, t_{test} = 10 \text{ s}, (see Fig. 2)$	V_{pd}	1.424	kV _{peak}

Note

• As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

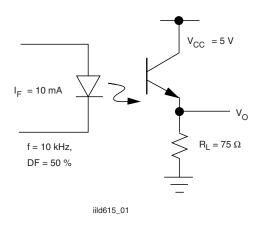


Fig. 1 Non-Saturated Switching Timing

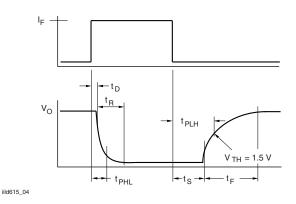


Fig. 5 - Saturated Switching Timing

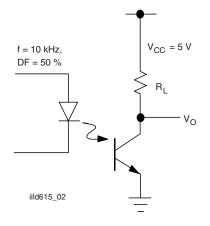


Fig. 3 - Saturated Switching Timing

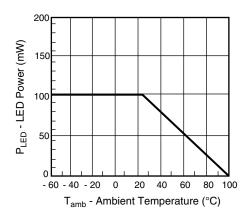


Fig. 6 - Maximum LED Power Dissipation

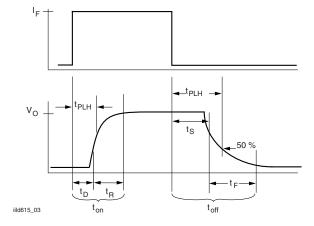


Fig. 4 - Non-Saturated Switching Timing

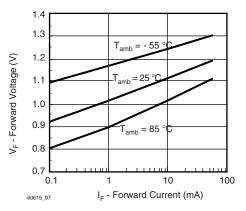


Fig. 7 - Forward Voltage vs. Forward Current





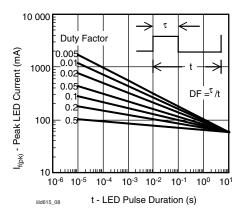


Fig. 8 - Peak LED Current vs. Pulse Duration, τ

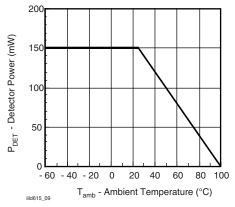


Fig. 9 - Maximum Detector Power Dissipation

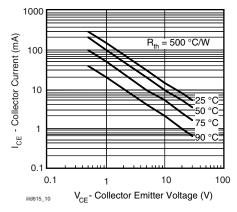


Fig. 10 - Maximum Collector Current vs. Collector Voltage

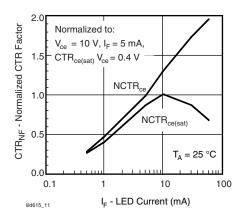


Fig. 11 - Normalization Factor for Non-Saturated and Saturated CTR vs. I_F

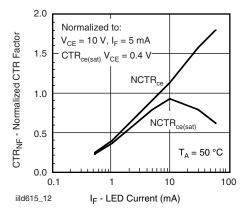


Fig. 12 - Normalization Factor for Non-Saturated and Saturated CTR vs. $I_{\rm F}$

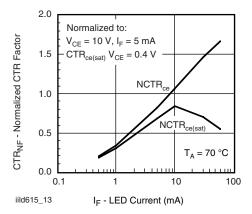


Fig. 13 - Normalization Factor for Non-Saturated and Saturated CTR vs. $I_{\rm F}$





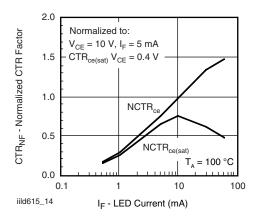


Fig. 14 - Normalization Factor for Non-Saturated and Saturated CTR vs. I_{F}

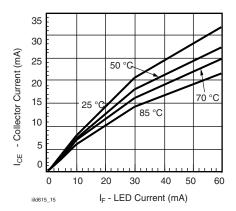


Fig. 15 - Collector Emitter Current vs. Temperature and LED Current

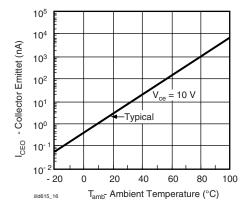


Fig. 16 - Collector Emitter Leakage vs. Temperature

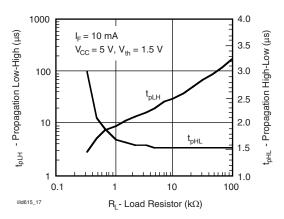


Fig. 17 - -1, Propagation Delay vs. Collector Load Resistor

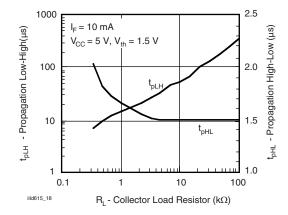


Fig. 18 - -2, -3, Propagation Delay vs. Collector Load Resistor

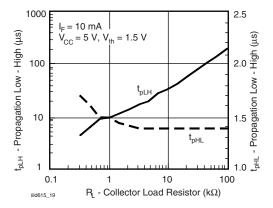
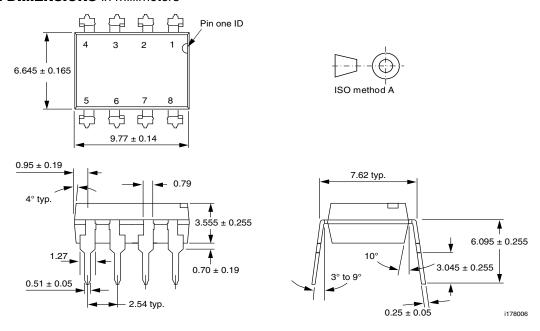


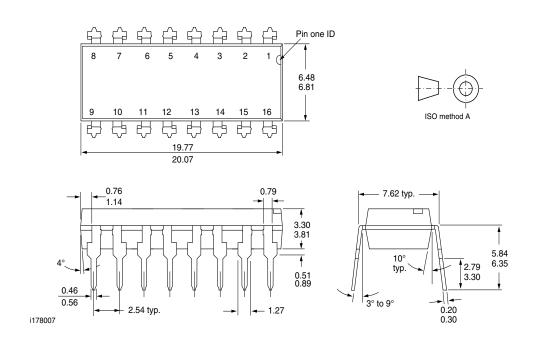
Fig. 19 - -4, Propagation Delay vs. Collector Load Resistor

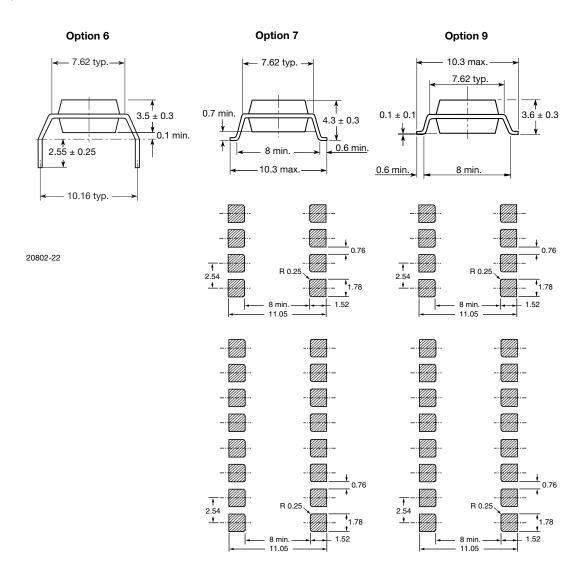
ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



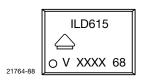
PACKAGE DIMENSIONS in millimeters







PACKAGE MARKING (example)



Notes

- XXXX = LMC (lot marking code)
- Only options 1 and 7 reflected in the package marking
- The VDE Logo is only marked on option1 parts
- Tape and reel suffix (T) is not part of the package marking



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Vishay

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